Ordering number : ENN2960A



# ON Semiconductor DATA SHEET

2SC4002 — NPN Triple Diffused Planar Silicon Transistor
High-Voltage Driver Applications

#### **Features**

- · High breakdown voltage.
- · Adoption of MBIT process.
- · Excellent hFE linearity.

## **Specifications**

### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		400	V
Collector-to-Emitter Voltage	VCEO		400	V
Emitter-to-Base Voltage	VEBO		5	٧
Collector Current	IC		200	mA
Collector Current (Pulse)	ICP		400	mA
Collector Dissipation	PC		600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	01111
Collector Cutoff Current	ICBO	VCB=300V, IE=0			0.1	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =4V, I <sub>C</sub> =0			0.1	μΑ
DC Current Gain	hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =50mA	60*		200*	
Gain-Bandwidth Product	fT	VCE=30V, IC=10mA		70		MHz
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=50mA, IB=5mA			0.6	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =50mA, I <sub>B</sub> =5mA			1.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0	400			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =10μA, I <sub>C</sub> =0	5			V
Output Capacitance	Cob	V <sub>CB</sub> =30V, f=1MHz		4		pF
Reverse Transfer Capacitance	C <sub>re</sub>	V <sub>CB</sub> =30V, f=1MHz		3		pF

<sup>\*:</sup> The 2SC4002 is classified by 50mA hFE as follows:

 Rank
 D
 E

 hFE
 60 to 120
 100 to 200

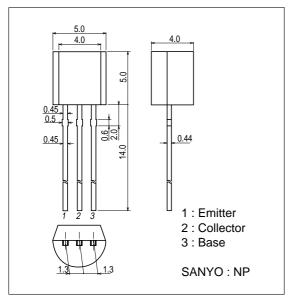
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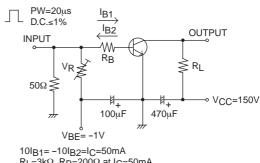
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	J OILL
Turn-ON Time	t <sub>on</sub>	See specified test circuit.		0.25		μS
Turn-OFF Time	toff	See specified test circuit.		5.0		μS

## **Package Dimensions**

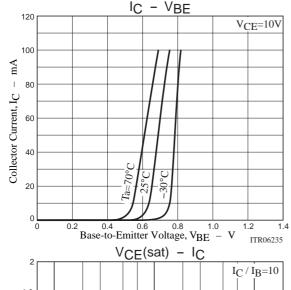
unit: mm 2003B

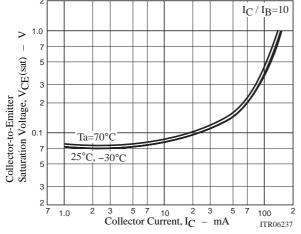


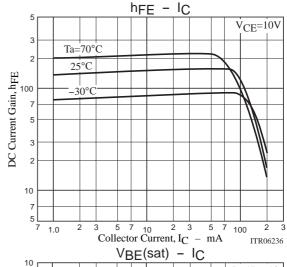
### **Switching Time Test Circuit**

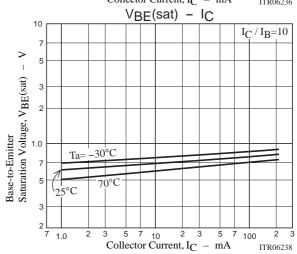


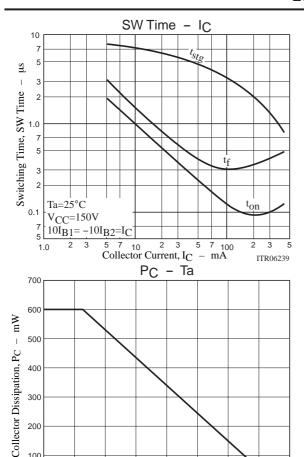
10I<sub>B1</sub>= -10I<sub>B2</sub>=I<sub>C</sub>=50mA R<sub>L</sub>=3k $\Omega$ , R<sub>B</sub>=200 $\Omega$  at I<sub>C</sub>=50mA



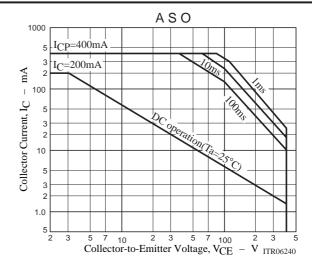








Ambient Temperature, Ta -



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